# NSN 5961-00-958-4836

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**Inclosure Material:** 

Metal

**Overall Length:** 

0.450 inches

## **Overall Diameter:**

0.875 inches

## **Mounting Facility Quantity:**

2

## Internal Configuration:

Junction contact

## Electrode Internally-electrically Connected To Case:

Collector

#### **Mounting Method:**

Unthreaded hole

Features Provided:

#### Hermetically sealed case

#### Semiconductor Material:

Germanium

## Voltage Rating In Volts Per Characteristic:

40.0 breakdown voltage, collector-to-base, emitter open and 30.0 breakdown voltage, collector-to-emitter, base open and 20.0

breakdown voltage, emitter-to-base, collector open

## **Current Rating Per Characteristic:**

5.00 amperes source cutoff current

#### Maximum Operating Tempurature Per Measurement Point:

100.0 degrees celsius junction

#### **Special Features:**

Junction pattern arrangement: pnp

#### **Terminal Type And Quantity:**

2 uninsulated wire lead and 1 case

#### **Specification Data:**

80131-release2903 professional/industrial association specification

#### Shelf Life:

N/a

#### Unit Of Measure:

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#### Demilitarization:

No

#### Fiig:

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